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APPLICANTS

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** CONTINUING DATA ***** None AICS

** FOREIGN APPLICATIONS ***** Yes AICS
 JAPAN P2003-079387 03/24/2003

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Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no	STATE OR COUNTRY JAPAN	SHEETS DRAWING 8	TOTAL CLAIMS 20	INDEPENDENT CLAIMS 3
35 USC 119 (a-d) conditions met <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance				
Verified and Acknowledged Examiner's Signature: <i>Asitha</i> Initials: <i>AS</i>				

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TITLE

Group-III nitride semiconductor stack, method of manufacturing the same, and group-III nitride semiconductor device

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